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Supramolecular Donor–Acceptor Heterojunctions by Vectorial Stepwise Assembly of Porphyrins and Coordination-Bonded Fullerene Arrays for **Photocurrent Generation**

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Bicontinuous donor-acceptor (D-A) arrays at the molecular level have attracted increasing scientific and technological interest because of their potential applications in organic photovoltaics.¹ Such D-A arrays would yield efficient charge separation (CS) and transportation of separated charges to their respective electrodes, leading to enhanced photocurrent generation provided that the vertical arrangement of the D-A arrays on the electrodes is ideal. Although nanostructures with bicontinuous D-A arrays have been obtained by self-assembly of D-A molecules,² it is still difficult to achieve the desirable vertical arrangement of bicontinuous D-A arrays on an electrode.3 Here we report a novel approach for constructing a vertical alignment of bicontinuous D-A arrays on a flat SnO₂ electrode for use as a photoelectrochemical device (Figure 1). A Pd-mediated stepwise self-assembly of zinc porphyrin (ZnP) donors ensures the vertical growth of porphyrin chains on the SnO₂ electrode.⁴ Pyridylfullerene (Py-C₆₀) acceptors are infiltrated into the porphyrin brush using coordination of the pyridyl moiety to the zinc atom together with $\pi - \pi$ interactions between the Py-C₆₀ moieties.⁵ Therefore, we can systematically investigate the relationship between the film structure and the photoelectrochemical properties as a function of the number of porphyrin layers.

A SnO₂ electrode was modified with ZnP arrays as follows. A thin, nonporous SnO₂ film with a roughness factor of 1.1 was prepared on an FTO electrode.⁶ The assembly of ZnP arrays on the SnO₂ electrode was performed by a procedure similar to that described by Qian et al.^{4b} (Scheme S1 in the Supporting Information). First, pyridylporphyrin acid (Py-ZnP-acid; Figure S1) was adsorbed on the surface of the SnO2 electrode through the carboxylic group. Next came Pd(II) coordination to the pyridyl group of the adsorbed Py-ZnP-acid followed by coordination of bis(pyridyl)porphyrin (ZnP-Py₂) to the Pd atom. The number of porphyrin layers could be controlled by the number of cycles of ZnP-Py₂ deposition via coordination between the pyridyl groups and Pd(II). Consequently, ZnP arrays were formed on the SnO₂ electrode; this structure is denoted as $\text{SnO}_2/(\text{ZnP})_n$, where n = 1-8 is the number of porphyrin layers. Figure S2a displays UV-vis absorption spectra measured after each assembly of a porphyrin layer on the electrode. The absorption due to the porphyrin increased with the number of deposition cycles, implying the successive growth of porphyrin chains. The amount of assembled porphyrins exhibited a linear

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Figure 1. Schematic porphyrin-fullerene arrays on a SnO₂ electrode.

increase as the number of layers of porphyrins increased and leveled off at n = 8 (Figure S3).

Assembly of ZnP-C₆₀ composites was also performed on the SnO₂ electrode following Scheme S2 in the Supporting Information. First, Py-ZnP-acid and C₆₀-acid (Figure S1) were simultaneously adsorbed on the surface of the SnO2 electrode, and then successive assembly of ZnP-Py₂ layers was achieved as described above (Figure S2b); this structure is denoted as SnO_2/C_{60} -acid+(ZnP)_n. In addition, the SnO_2/C_{60} -acid+ $(ZnP)_n$ electrodes were immersed into an o-dichlorobenzene (ODCB) solution of Py-C₆₀, which coordinated to the zinc porphyrins⁵ and became incorporated into the porphyrin arrays (yielding SnO_2/C_{60} -acid+ $(ZnP)_n$ +Py-C₆₀). Treatment of the SnO_2/C_{60} -acid+(ZnP)_n electrodes with the solution of Py-C₆₀ resulted in a significant rise in the absorption around 320-400 nm stemming from the absorption of Py-C₆₀ together with the red shift of the Soret band (Figure S4a).⁵ This demonstrates the complexation of Py-C $_{60}$ and ZnP and the infiltration of Py-C $_{60}$ from top to bottom in the ZnP brushes. The SnO_2/C_{60} -acid+ $(ZnP)_n$ electrodes were also treated with an ODCB solution of Ph-C₆₀ (Figure S1), which bears a phenyl rather than a pyridyl moiety. A slight rise in the absorption around 320-400 nm and no red shift were observed for the SnO₂/C₆₀-acid+(ZnP)_n+Ph-C₆₀ electrode, suggesting the weak interpenetration of Ph-C₆₀ into the ZnP arrays due solely to $\pi - \pi$ interactions between Ph-C₆₀ units^{1c} (Figure S4b). The infiltrated amount of X-C₆₀ (X = Py, Ph) was determined by measuring the increase in absorbance of the electrodes at 375 nm resulting from the modification with X-C₆₀: $[ZnP]/[Py-C_{60}] = 1:3$ to 1:4 (n = 2-6) for the SnO₂/C₆₀-acid+(ZnP)_n+Py-C₆₀ electrodes

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and [ZnP]/[Ph-C₆₀] = 1:1 to 1:2 (n = 2-6) for the SnO₂/C₆₀acid+(ZnP)_n+Ph-C₆₀ electrodes (Figure S5). The increased ratio for Py-C₆₀ relative to Ph-C₆₀ implies that the coordination in addition to the $\pi-\pi$ interactions contributes greatly to the infiltration. Steadystate fluorescence experiments revealed intense quenching of the porphyrin fluorescence for the SnO₂/C₆₀-acid+(ZnP)_n+Py-C₆₀ electrodes compared with that of the reference without the C₆₀ molecules (Figure S6). These results suggest that the porphyrin excited singlet state (¹ZnP*) is quenched via electron transfer (ET) to the Py-C₆₀ interpenetrated into the ZnP arrays.^{1c,2e,5} A weak emission around 700–800 nm may be attributed to the direct excitation of the C₆₀ molecules incorporated into the ZnP arrays due to $\pi-\pi$ interactions between C₆₀ molecules.⁷

The average thickness of the porphyrin arrays was evaluated using transmission electron microscopy (TEM) measurements on SnO₂ nanoparticles modified with the porphyrin arrays (Figure S7 in the Supporting Information). Close inspection of the TEM images showed that the thickness linearly increased as the number of porphyrin layers increased, indicating the linear elongation of the porphyrin chains. From a comparison of the film thicknesses and the lengths of the porphyrin arrays estimated from the sizes of porphyrins and Pd complexes (Table S1 and Figure S8), the orientation angle (θ) between the porphyrin arrays and the SnO₂ surface is estimated as $28 \pm 5^{\circ}$, which is consistent with the value for similar porphyrin arrays on quartz substrates.^{4b} A similar trend is noted for SnO2 nanoparticles further modified with C60-acid and Py-C₆₀ (Table S1). Atomic force microscopy (AFM) measurements were performed for the SnO_2 films modified with ZnP and C_{60} (Figure S9). The images of the $SnO_2/(ZnP)_n$ and SnO_2/C_{60} acid+(ZnP)n+Ph-C60 substrates exhibited domain structures that would result from aggregation between the porphyrin chains, whereas those of the SnO_2/C_{60} -acid+ $(ZnP)_n$ +Py-C₆₀ (n = 2-5) substrates disclosed a smooth surface morphology. In D-A blend films, such as conjugated polymer-fullerene derivative films in bulk heterojunction solar cells, an intimate mixing of the components leads to a smooth surface morphology of the film, which can be confirmed by using AFM.¹ Accordingly, the incorporation of Py-C₆₀ molecules into the ZnP arrays suppresses the porphyrin aggregation, yielding the D-A bicontinuous arrays on the SnO₂ electrode.8

Figure S10 in the Supporting Information depicts the photocurrent action spectra for the modified electrodes, which closely resemble the corresponding absorption spectra of the electrodes (Figure S2). The incident photon-to-current efficiency (IPCE) and absorbed photon-to-current efficiency (APCE) values for the $SnO_2/(ZnP)_n$ electrodes at 440 nm are plotted as functions of n in Figure 2a and Figure S11a, respectively. As n increased, both the IPCE and APCE values increased to reach maxima for n =3 and then decreased gradually. As established previously, 1c,2e,8 ¹ZnP* injects electrons into the conduction band (CB) of SnO₂, after which ET from I⁻ to the zinc porphyrin radical cation (ZnP^{•+}) occurs, generating a photocurrent (Scheme S3). The trend is reasonable, considering that the exciton diffusion length (~ 6 nm) of the porphyrin arrays, corresponding to the number of porphyrins and the total length (n = 3), is comparable to that of copper phthalocyanine (8 \pm 3 nm) in bulk heterojunction solar cells.⁹ It is noteworthy that for the SnO_2/C_{60} -acid+ $(ZnP)_n$ +Py-C₆₀ electrodes, the trends in the IPCE and APCE values as functions of n (Figures 2b and S11b) parallel that in the amount of Py-C₆₀ infiltrated as a function of n.¹⁰ A similar trend is noted for the SnO_2/C_{60} -acid+ $(ZnP)_n$ +Ph-C₆₀ electrodes.

The photodynamics of the photoinduced CS processes was studied by femtosecond time-resolved transient absorption measure-



Figure 2. Plots of the IPCE values as functions of the number of porphyrin layers for (a) $\text{SnO}_2/(\text{ZnP})_n$ (solid line with filled circles) and (b) SnO_2/C_{60} -acid+(ZnP)_n (dotted line with open circles), SnO_2/C_{60} -acid+(ZnP)_n+Ph-C₆₀ (dashed line with triangles), and SnO_2/C_{60} -acid+(ZnP)_n+Py-C₆₀ (solid line with crosses). Input power, 63 μ W cm⁻² (λ_{ex} = 440 nm); applied potential, 0.05 V vs SCE; 0.5 M LiI and 0.01 M I₂ in acetonitrile.



Figure 3. Transient absorption spectra of SnO_2/C_{60} -acid+ $(ZnP)_7$ +Py- C_{60} (solid line) and $SnO_2/(ZnP)_7$ (dotted line) electrodes at time delay of 1 ps after laser excitation at 560 nm. The spectrum of the $SnO_2/(ZnP)_7$ electrode was normalized to that of the SnO_2/C_{60} -acid+ $(ZnP)_7$ +Py- C_{60} electrode at 500 nm for comparison.

ments (Figure 3). The bleaching at 620 nm arises from ${}^{1}ZnP^{*}$,¹¹ whereas the broad absorption at ~660 nm originates from zinc porphyrin radical cation (ZnP⁺⁺).¹¹ Although ${}^{1}ZnP^{*}$ and ZnP⁺⁺ appear simultaneously, the large Δ (absorbance) of SnO₂/C₆₀-acid+(ZnP)₇+Py-C₆₀ relative to that of SnO₂/(ZnP)₇ at ~660 nm exemplifies the additional contribution of the CS between ZnP and C₆₀ to the enhancement in the photocurrent generation. This is consistent with the fact that the APCE value of the SnO₂/C₆₀-acid+(ZnP)₇+Py-C₆₀ system (7.1% at 560 nm) is larger than that

Scheme 1. (a) Schematic Illustration of Photocurrent Generation in the SnO_2/C_{60} -acid+ $(ZnP)_n$ +Py- C_{60} System and (b) Its Energy Diagram^a



 a The levels of C₆₀-acid and Py-C₆₀ were determined electrochemically from the first reduction potentials of C₆₀-acid and Py-C₆₀ in chloroform.

of the SnO₂/(ZnP)₇ system (5.0% at 560 nm). That is, exciton and carrier loss in the porphyrin arrays is suppressed as a result of exciton capture and charge dissociation by C₆₀, which can rationalize the fact that the maximum IPCE and APCE values were attained at a greater number of porphyrin layers for the SnO₂/C₆₀acid+ $(ZnP)_n$ +Py-C₆₀ system (n = 5) than for the SnO₂/ $(ZnP)_n$ system (n = 3). The decreasing trend of the IPCE and APCE values in the SnO₂/C₆₀-acid+(ZnP)₇+Py-C₆₀ system for n = 6-8 correlates with the decreasing amount of C60 molecules incorporated between the porphyrin brushes, which arises from the porphyrin aggregation, as seen in the AFM measurements (see above).¹⁰ In such a case, the efficiency of CS between ¹ZnP* and C₆₀ would decrease with increasing *n*, leading to the decrease in the IPCE and APCE values. On the basis of the film structures and the photoelectrochemical properties of the SnO₂/C₆₀-acid+(ZnP)_n+Py-C₆₀ systems together with the previously established photocurrent generation mechanism in similar porphyrin-fullerene composites on semiconducting electrodes, $1^{1c,2e,8}$ we can propose the photocurrent generation diagram shown in Scheme 1. First, CS between ¹ZnP* and C₆₀ takes place in addition to direct electron injection from ¹ZnP* to the CB of the SnO₂. In the former case, the generated $C_{60}^{\bullet-}$ injects electrons into the CB of the SnO2 via electron hopping through the C60 molecules infiltrated from top to bottom in the porphyrin brushes. Thus, the bicontinuous D-A arrays for the SnO_2/C_{60} -acid+ $(ZnP)_n$ +Py- C_{60} (n = 2-6) electrodes are responsible for the enhancement of photocurrent generation.

In conclusion, we have successfully developed a novel strategy for constructing a vertical arrangement of D-A arrays on a semiconducting electrode. The relationship between the film structure and photoelectrochemical properties has been elucidated as a function of the number of donor layers for the first time. The maximum IPCE value (21%) is comparable to the highest value (20%) reported for vertical arrangements of bicontinuous D–A arrays on electrodes.³ These results will provide fundamental clues for the molecular design of high-performance organic photovoltaics.

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Supporting Information Available: Complete ref 2e, experimental details, Schemes S1–S3, Table S1, and Figures S1–S11. This material is available free of charge via the Internet at http://pubs.acs.org.

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